MC34064, MC33064, NCV33064

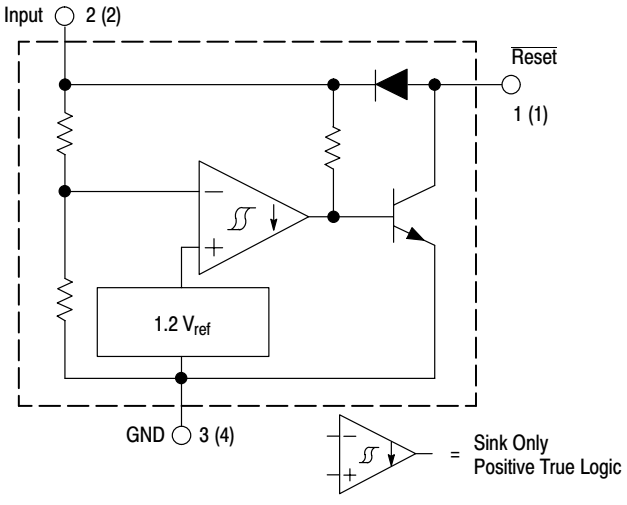
Undervoltage Sensing Circuit

The MC34064 is an undervoltage sensing circuit specifically designed for use as a reset controller in microprocessor−based systems. It offers the designer an economical solution for low voltage detection with a single external resistor. The MC34064 features a trimmed−in−package bandgap reference, and a comparator with precise thresholds and built-in hysteresis to prevent erratic reset operation. The open collector reset output is capable of sinking in excess of 10 mA, and operation is guaranteed down to 1.0 V input with low standby current. The MC devices are packaged in 3−pin TO-92, micro size TSOP−5, 8−pin SOIC−8 and Micro8™ surface mount packages. The NCV device is packaged in SOIC−8 and TO−92.

Applications include direct monitoring of the 5.0 V MPU/logic power supply used in appliance, automotive, consumer and industrial equipment.

Features

- Trimmed−In−Package Temperature Compensated Reference
- Comparator Threshold of 4.6 V at 25°C
- Precise Comparator Thresholds Guaranteed Over Temperature
- Comparator Hysteresis Prevents Erratic Reset
- Reset Output Capable of Sinking in Excess of 10 mA
- Internal Clamp Diode for Discharging Delay Capacitor
- Guaranteed Reset Operation with 1.0 V Input
- Low Standby Current
- Economical TO−92, TSOP−5, SOIC−8 and Micro8 Surface Mount Packages
- NCV Prefix for Automotive and Other Applications Requiring Site and Control Changes
- Pb−Free Packages are Available



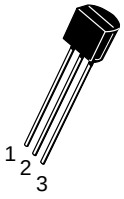
Pin numbers adjacent to terminals are for the 3−pin TO−92 package.
Pin numbers in parenthesis are for the 8−lead packages.

This device contains 21 active transistors.

Figure 1. Representative Block Diagram

ON Semiconductor®

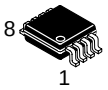
http://onsemi.com



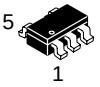
TO−92
P SUFFIX
CASE 29

Pin 1. $\overline{\text{Reset}}$
2. Input
3. Ground

SOIC−8
D SUFFIX
CASE 751



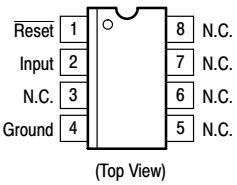
Micro8
DM SUFFIX
CASE 846A



TSOP−5
SN SUFFIX
CASE 483

Pin 1. $\overline{\text{Reset}}$
2. Input
3. Ground
4. NC
5. NC

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 7 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Input Supply Voltage	V_{in}	−1.0 to 10	V
$\overline{\text{Reset}}$ Output Voltage	V_O	10	V
$\overline{\text{Reset}}$ Output Sink Current (Note 2)	I_{Sink}	Internally Limited	mA
Clamp Diode Forward Current, Pin 1 to 2 (Note 2)	I_F	100	mA
Power Dissipation and Thermal Characteristics P Suffix, Plastic Package Maximum Power Dissipation @ T_A = 25°C Thermal Resistance, Junction−to−Air D Suffix, Plastic Package Maximum Power Dissipation @ T_A = 25°C Thermal Resistance, Junction−to−Air DM Suffix, Plastic Package Maximum Power Dissipation @ T_A = 25°C Thermal Resistance, Junction−to−Air	 P_D $R_{\theta JA}$ P_D $R_{\theta JA}$ P_D $R_{\theta JA}$	 625 200 625 200 520 240	 mW °C/W mW °C/W mW °C/W
Operating Junction Temperature	T_J	+150	°C
Operating Ambient Temperature MC34064 MC33064 NCV33064	T_A	 0 to +70 −40 to +85 −40 to +125	°C
Storage Temperature Range	T_{stg}	−65 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. ESD data available upon request.

ELECTRICAL CHARACTERISTICS (For typical values T_A = 25°C, for min/max values T_A is the operating ambient temperature range that applies [Notes 3 and 4] unless otherwise noted.)

Characteristics	Symbol	Min	Typ	Max	Unit
COMPARATOR					
Threshold Voltage High State Output (V_{in} Increasing) Low State Output (V_{in} Decreasing) Hysteresis	 V_{IH} V_{IL} V_H	 4.5 4.5 0.01	 4.61 4.59 0.02	 4.7 4.7 0.05	V
$\overline{\text{RESET}}$ OUTPUT					
Output Sink Saturation (V_{in} = 4.0 V, I_{Sink} = 8.0 mA) (V_{in} = 4.0 V, I_{Sink} = 2.0 mA) (V_{in} = 1.0 V, I_{Sink} = 0.1 mA)	V_{OL}	 − − −	 0.46 0.15 −	 1.0 0.4 0.1	V
Output Sink Current (V_{in}, $\overline{\text{Reset}}$ = 4.0 V)	I_{Sink}	10	27	60	mA
Output Off-State Leakage (V_{in}, $\overline{\text{Reset}}$ = 5.0 V)	I_{OH}	−	0.02	0.5	μA
Clamp Diode Forward Voltage, Pin 1 to 2 (I_F = 10 mA)	V_F	0.6	0.9	1.2	V
TOTAL DEVICE					
Operating Input Voltage Range	V_{in}	1.0 to 6.5	−	−	V
Quiescent Input Current (V_{in} = 5.0 V)	I_{in}	−	390	500	μA

2. Maximum package power dissipation limits must be observed.
3. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient as possible.
4. T_{low} = 0°C for MC34064, −40°C for MC33064, −40°C for NCV33064; T_{high} = +70°C for MC34064, +85°C for MC33064, +125°C for NCV33064
5. NCV prefix is for automotive and other applications requiring site and change control.

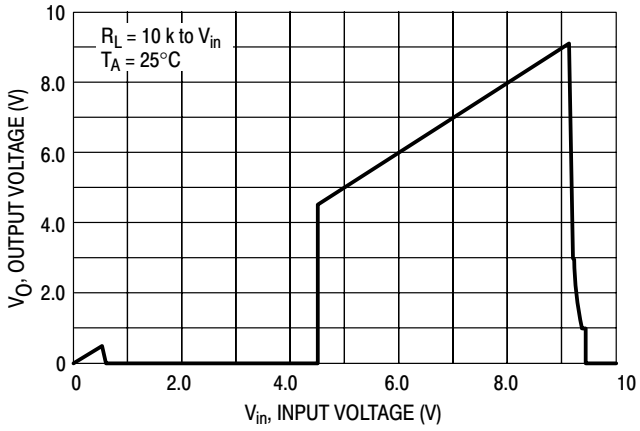


Figure 2. $\overline{\text{Reset}}$ Output Voltage versus Input Voltage

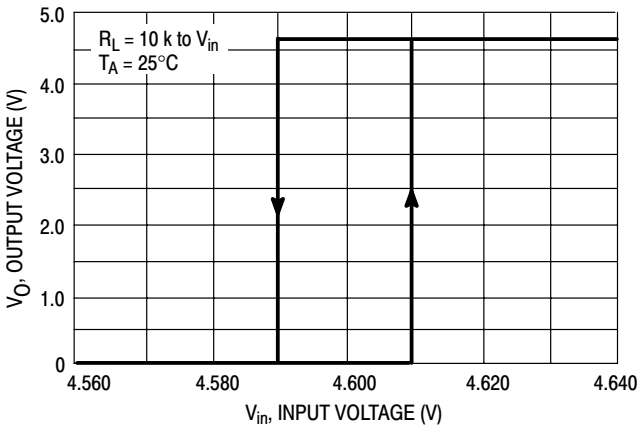


Figure 3. $\overline{\text{Reset}}$ Output Voltage versus Input Voltage

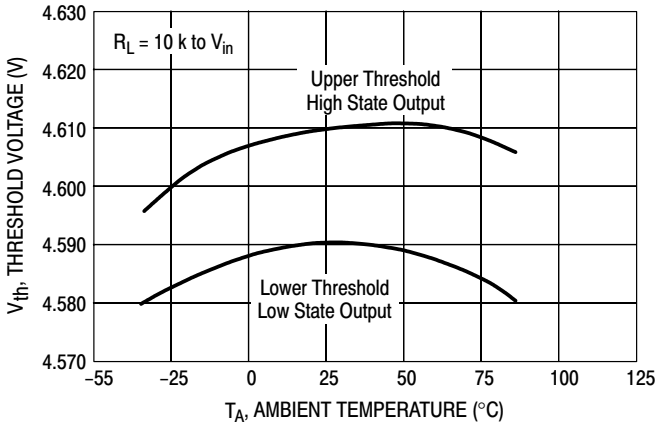


Figure 4. Comparator Threshold Voltage versus Temperature

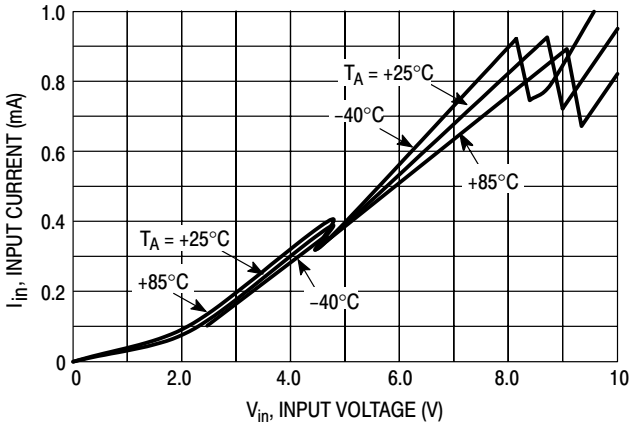


Figure 5. Input Current versus Input Voltage

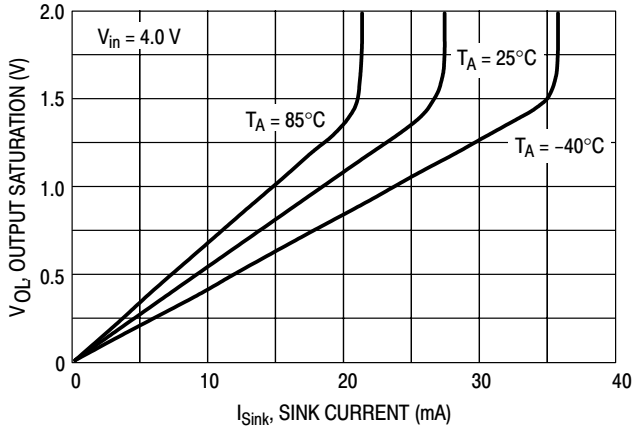


Figure 6. $\overline{\text{Reset}}$ Output Saturation versus Sink Current

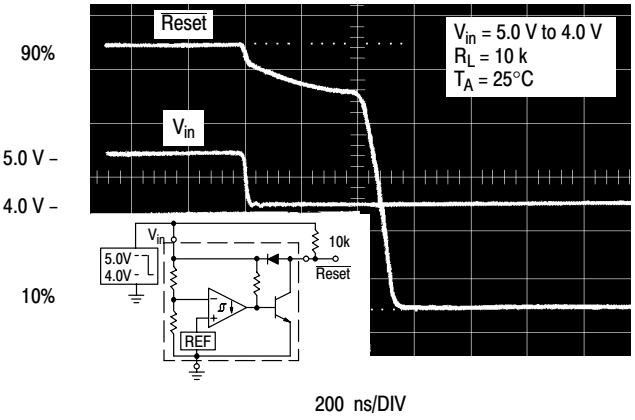


Figure 7. $\overline{\text{Reset}}$ Delay Time

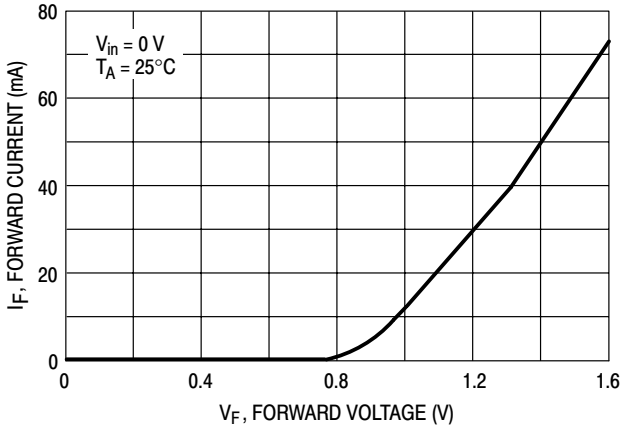


Figure 8. Clamp Diode Forward Current versus Voltage

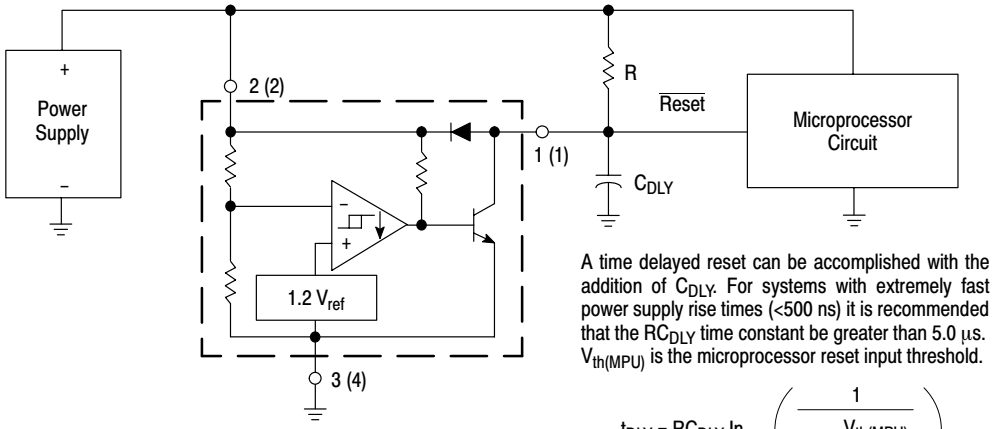
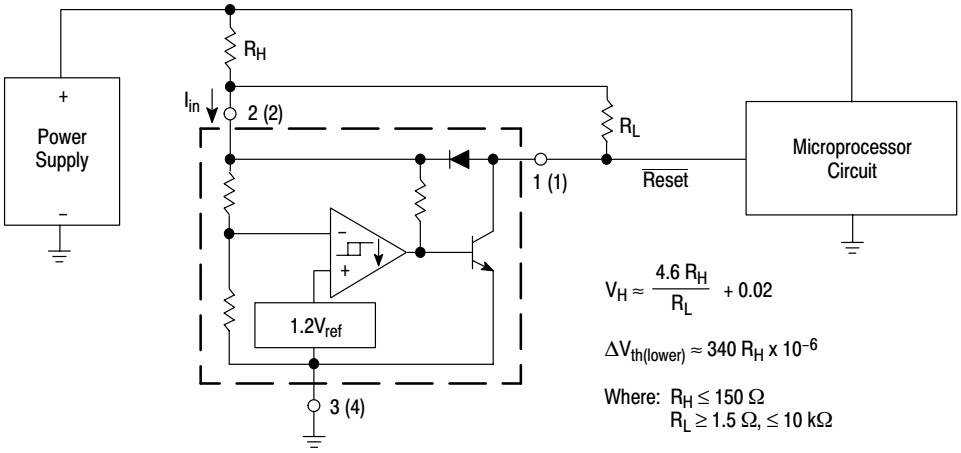


Figure 9. Low Voltage Microprocessor Reset



TEST DATA

V_H (mV)	ΔV_{th} (mV)	R_H (Ω)	R_L (kΩ)
20	0	0	0
51	3.4	10	1.5
40	6.8	20	4.7
81	6.8	20	1.5
71	10	30	2.7
112	10	30	1.5
100	16	47	2.7
164	16	47	1.5
190	34	100	2.7
327	34	100	1.5
276	51	150	2.7
480	51	150	1.5

Comparator hysteresis can be increased with the addition of resistor R_H. The hysteresis equation has been simplified and does not account for the change of input current I_{in} as V_{CC} crosses the comparator threshold (Figure 4). An increase of the lower threshold $\Delta V_{th(lower)}$ will be observed due to I_{in} which is typically 340 μA at 4.59 V. The equations are accurate to ±10% with R_H less than 150 Ω and R_L between 1.5 kΩ and 10 kΩ.

Figure 10. Low Voltage Microprocessor Reset with Additional Hysteresis

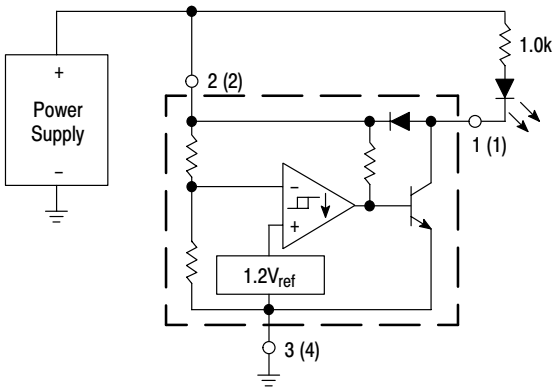


Figure 11. Voltage Monitor

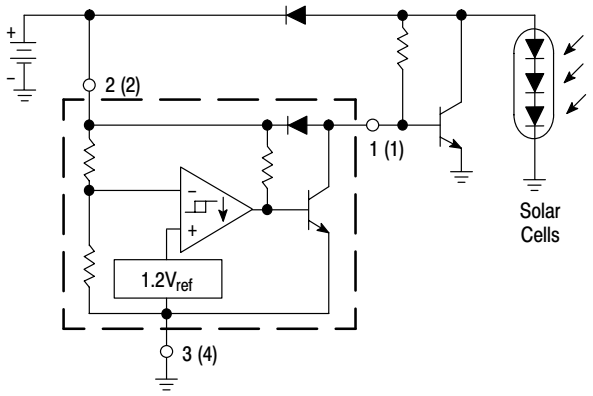
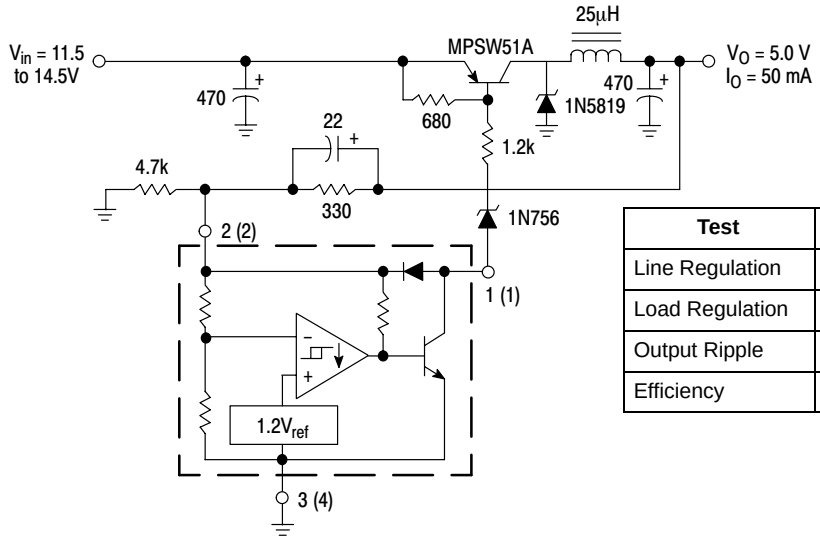
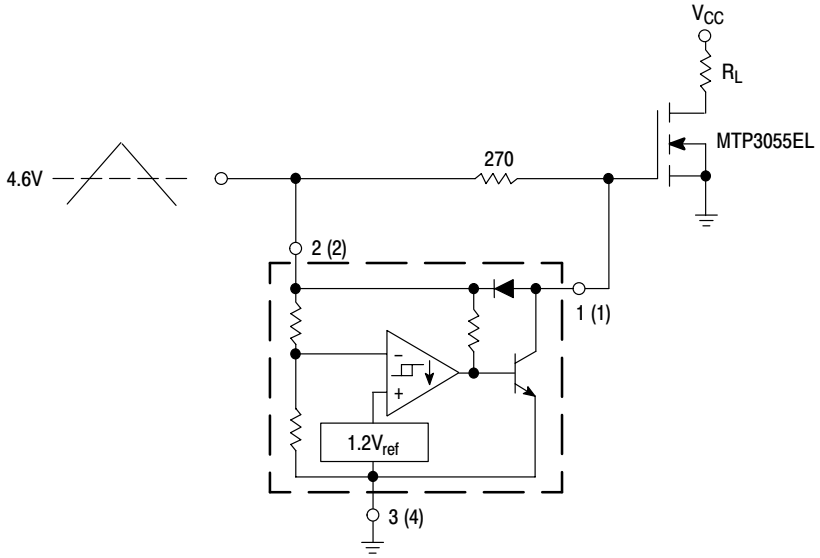


Figure 12. Solar Powered Battery Charger



Test	Conditions	Results
Line Regulation	V_{in} = 11.5 V to 14.5 V, I_O = 50 mA	35 mV
Load Regulation	V_{in} = 12.6 V, I_O = 0 mA to 50 mA	12 mV
Output Ripple	V_{in} = 12.6 V, I_O = 50 mA	60 mVpp
Efficiency	V_{in} = 12.6 V, I_O = 50 mA	77%

Figure 13. Low Power Switching Regulator



Overheating of the logic level power MOSFET due to insufficient gate voltage can be prevented with the above circuit. When the input signal is below the 4.6 V threshold of the MC34064, its output grounds the gate of the L^2 MOSFET.

Figure 14. MOSFET Low Voltage Gate Drive Protection

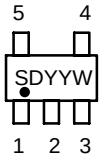
ORDERING INFORMATION

Device	Operating Temperature Range	Package	Shipping
MC34064D−005	T_A = 0°C to +70°C	SOIC−8	98 Units / Rail
MC34064D−005G		SOIC−8 (Pb−Free)	98 Units / Rail
MC34064D−5R2		SOIC−8	2500 Units/ Tape & Reel
MC34064D−5R2G		SOIC−8 (Pb−Free)	2500 Units/ Tape & Reel
MC34064DM−5R2		Micro8	4000 Units / Tape & Reel
MC34064DM−5R2G		Micro8 (Pb−Free)	4000 Units / Tape & Reel
MC34064P−005		TO−92	2000 Units / Bag
MC34064P−005G		TO−92 (Pb−Free)	2000 Units / Bag
MC34064P−5RA		TO−92	2000 Units / Tape & Reel
MC34064P−5RAG		TO−92 (Pb−Free)	2000 Units / Tape & Reel
MC34064P−5RP		TO−92	2000 Units / Ammo Pack
MC34064P−5RPG		TO−92 (Pb−Free)	2000 Units / Ammo Pack
MC34064P−5RM		TO−92	2000 Units / Ammo Pack
MC34064SN−5T1		TSOP−5	3000 Units / Tape & Reel
MC33064D−005	T_J = −40°C to +85°C	SOIC−8	98 Units / Rail
MC33064D−005G		SOIC−8 (Pb−Free)	98 Units / Rail
MC33064D−5R2		SOIC−8	2500 Units / Tape & Reel
MC33064D−5R2G		SOIC−8 (Pb−Free)	2500 Units / Tape & Reel
MC33064DM−5R2		Micro8	4000 Units / Tape & Reel
MC33064DM−5R2G		Micro8 (Pb−Free)	4000 Units / Tape & Reel
MC33064P−005		TO−92	2000 Units / Bag
MC33064P−005G		TO−92 (Pb−Free)	2000 Units / Bag
MC33064P−5RA		TO−92	2000 Units / Tape & Reel
MC33064P−5RAG		TO−92 (Pb−Free)	2000 Units / Tape & Reel
MC33064P−5RP		TO−92	2000 Units / Ammo Pack
MC33064P−5RPG		TO−92 (Pb−Free)	2000 Units / Ammo Pack
NCV33064D−5R2*	T_A = −40°C to +125°C	SOIC−8	2500 Units / Tape & Reel
NCV33064D−5R2G*		SOIC−8 (Pb−Free)	2500 Units / Tape & Reel
NCV33064P−5RA*		TO−92	2000 Units / Tape & Reel
NCV33064P−5RP*		TO−92	2000 Units / Ammo Pack
NCV33064DM−5R2*		Micro8	4000 Units / Tape & Reel

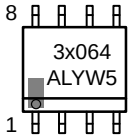
*NCV33064: T_{low} = −40°C, T_{high} = +125°C. Guaranteed by design. NCV prefix is for automotive and other applications requiring site and change control.

MARKING DIAGRAMS

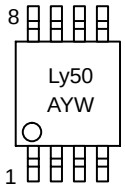
TSOP−5
SN SUFFIX
CASE 483



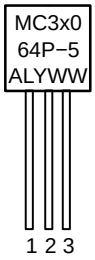
SOIC−8
D SUFFIX
CASE 751



Micro8
DM SUFFIX
CASE 846A



TO−92
P SUFFIX
CASE 29 *

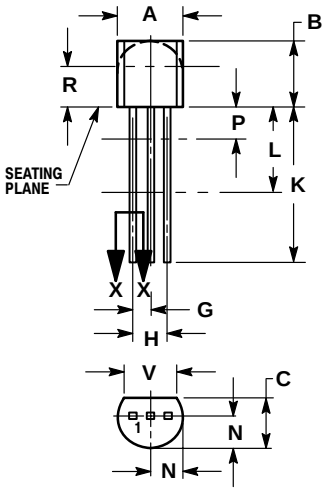


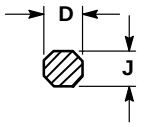
SDY = Device Code
x = 3 or 4
y = I or C
A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week

*This marking diagram also applies to NCV33064P.

PACKAGE DIMENSIONS

P SUFFIX
PLASTIC PACKAGE
CASE 29−11
(TO−92)
ISSUE AL





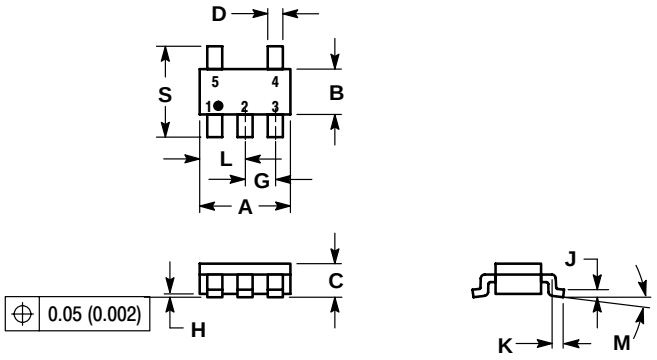
SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

PACKAGE DIMENSIONS

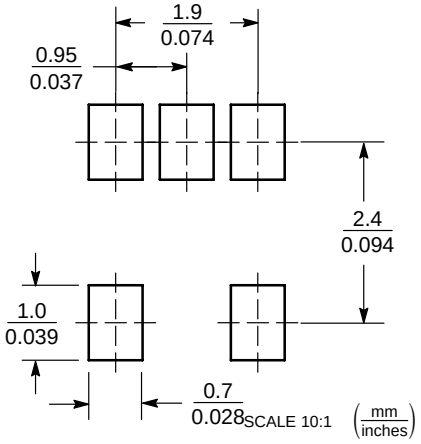
SN SUFFIX
PLASTIC PACKAGE
CASE 483−02
ISSUE C



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. A AND B DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

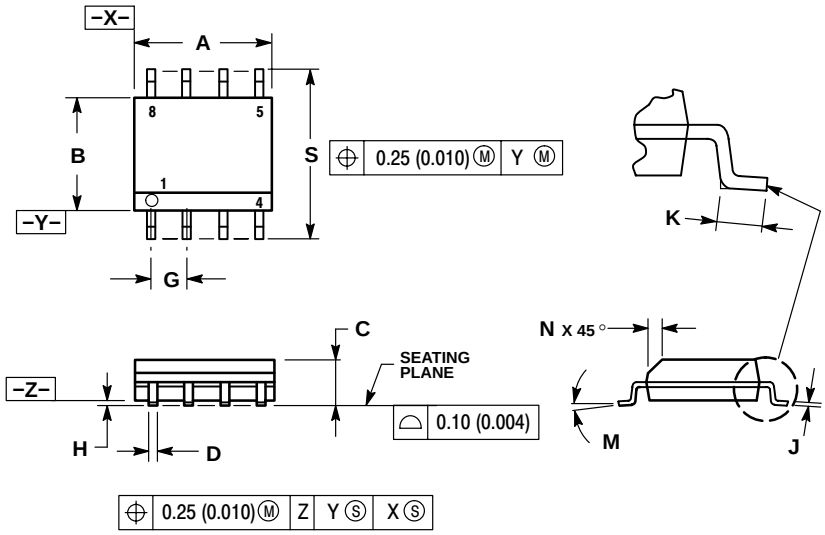
	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	2.90	3.10	0.1142	0.1220
B	1.30	1.70	0.0512	0.0669
C	0.90	1.10	0.0354	0.0433
D	0.25	0.50	0.0098	0.0197
G	0.85	1.05	0.0335	0.0413
H	0.013	0.100	0.0005	0.0040
J	0.10	0.26	0.0040	0.0102
K	0.20	0.60	0.0079	0.0236
L	1.25	1.55	0.0493	0.0610
M	0	10	0	10
S	2.50	3.00	0.0985	0.1181

SOLDERING FOOTPRINT



PACKAGE DIMENSIONS

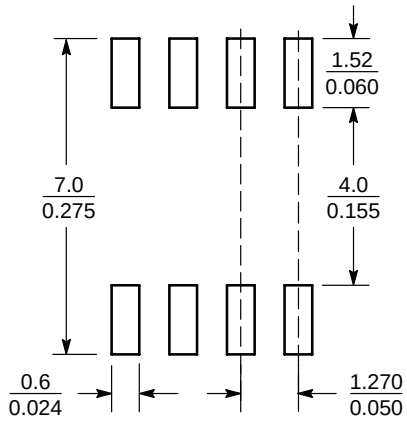
D SUFFIX
PLASTIC PACKAGE
CASE 751−07
(SOIC−8 NB)
ISSUE AE



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751−01 THRU 751−06 ARE OBSOLETE. NEW STANDARD IS 751−07.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*

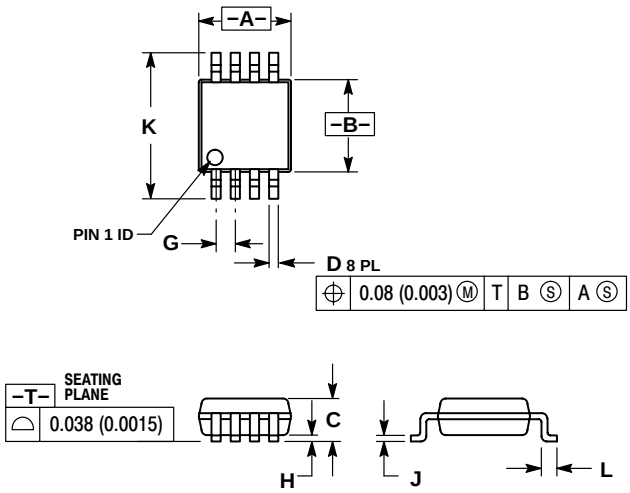


SCALE 6:1 (mm / inches)

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

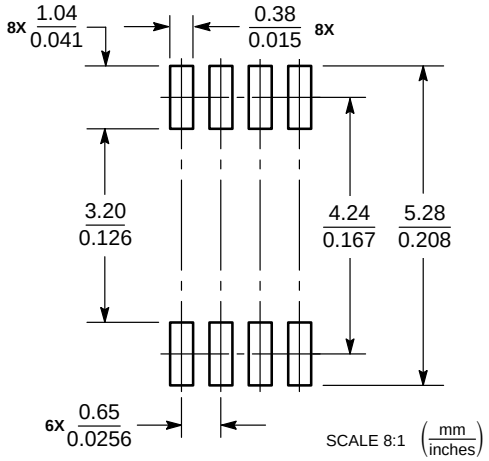
DM SUFFIX
PLASTIC PACKAGE
CASE 846A−02
(Micro8)
ISSUE F



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. 846A−01 OBSOLETE, NEW STANDARD 846A−02.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	---	1.10	---	0.043
D	0.25	0.40	0.010	0.016
G	0.65 BSC		0.026 BSC	
H	0.05	0.15	0.002	0.006
J	0.13	0.23	0.005	0.009
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

SOLDERING FOOTPRINT*



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